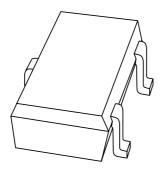
DISCRETE SEMICONDUCTORS

DATA SHEET



PMST2222; PMST2222A NPN switching transistors

Product data sheet Supersedes data of 1997 Jul 14 1999 Apr 22



NPN switching transistors

PMST2222; PMST2222A

FEATURES

- High current (max. 600 mA)
- Low voltage (max. 40 V).

APPLICATIONS

• High-speed switching and linear amplification.

DESCRIPTION

NPN switching transistor in a SOT323 plastic package. PNP complement: PMST2907A.

MARKING

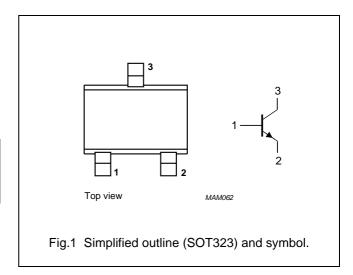
TYPE NUMBER	MARKING CODE(1)
PMST2222	*1B
PMST2222A	*1P

Note

* = - : Made in Hong Kong.
 * = t : Made in Malaysia.

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter			
	PMST2222		_	60	V
	PMST2222A		_	75	V
V _{CEO}	collector-emitter voltage	open base			
	PMST2222		_	30	V
	PMST2222A		_	40	V
V _{EBO}	emitter-base voltage	open collector			
	PMST2222		_	5	V
	PMST2222A		_	6	V
I _C	collector current (DC)		-	600	mA
I _{CM}	peak collector current		_	800	mA
I _{BM}	peak base current		_	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	-	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

1999 Apr 22

NPN switching transistors

PMST2222; PMST2222A

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	625	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 50 V	_	10	nA
	PMST2222	I _E = 0; V _{CB} = 50 V; T _j = 125 °C	_	10	μΑ
	collector cut-off current	I _E = 0; V _{CB} = 60 V	_	10	nA
	PMST2222A	I _E = 0; V _{CB} = 60 V; T _j = 125 °C	_	10	μΑ
I _{EBO}	collector cut-off current	I _C = 0; V _{EB} = 3 V	_	10	nA
h _{FE}	DC current gain	I _C = 0.1 mA; V _{CE} = 10 V	35	_	
		I _C = 1 mA; V _{CE} = 10 V	50	_	
		I _C = 10 mA; V _{CE} = 10 V	75	_	
		$I_C = 10 \text{ mA}; V_{CE} = 10 \text{ V}; T_{amb} = -55 ^{\circ}\text{C}$	35	_	
		I _C = 150 mA; V _{CE} = 1 V; note 1	50	_	
		I _C = 150 mA; V _{CE} = 10 V; note 1	100	300	
	DC current gain	I _C = 500 mA; V _{CE} = 10 V; note 1			
	PMST2222		30	_	
	PMST2222A		40	_	
V _{CEsat}	collector-emitter saturation voltage	I _C = 150 mA; I _B = 15 mA; note 1	_	400	mV
	PMST2222	$I_C = 500 \text{ mA}$; $I_B = 50 \text{ mA}$; note 1	_	1.6	V
	collector-emitter saturation voltage	I _C = 150 mA; I _B = 15 mA; note 1	_	300	mV
	PMST2222A	I _C = 500 mA; I _B = 50 mA; note 1	_	1	V
V _{BEsat}	base-emitter saturation voltage	I _C = 150 mA; I _B = 15 mA; note 1	_	1.3	V
	PMST2222	I _C = 500 mA; I _B = 50 mA; note 1	-	2.6	V
	base-emitter saturation voltage	I _C = 150 mA; I _B = 15 mA; note 1	0.6	1.2	V
	PMST2222A	$I_C = 500 \text{ mA}$; $I_B = 50 \text{ mA}$; note 1	_	2	V
C _c	collector capacitance	I _E = i _e = 0; V _{CB} = 10 V; f = 1 MHz	_	8	pF
Ce	emitter capacitance	$I_C = i_c = 0$; $V_{EB} = 0.5 \text{ V}$; $f = 1 \text{ MHz}$			
	PMST2222		_	30	pF
	PMST2222A		_	25	pF
f _T	transition frequency	I _C = 20 mA; V _{CE} = 20 V; f = 100 MHz			
	PMST2222		250	_	MHz
	PMST2222A		300	_	MHz

1999 Apr 22 3

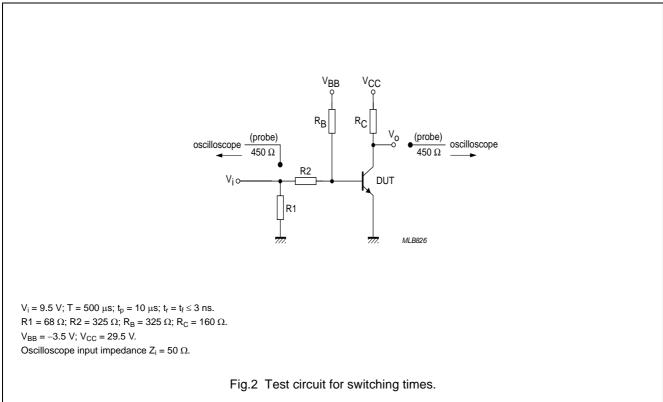
NPN switching transistors

PMST2222; PMST2222A

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
F	noise figure	I_C = 200 μA; V_{CE} = 5 V; R_S = 2 kΩ; f = 1 kHz; B = 200 Hz	_	4	dB
Switching t	mes (between 10% and 90% levels)); (see Fig.2)			
t _{on}	turn-on time	I _{Con} = 150 mA; I _{Bon} = 15 mA; I _{Boff} = -15 mA	_	35	ns
t _d	delay time		_	15	ns
t _r	rise time		_	20	ns
t _{off}	turn-off time		_	250	ns
t _s	storage time		_	200	ns
t _f	fall time		_	60	ns

Note

1. Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$



1999 Apr 22 4

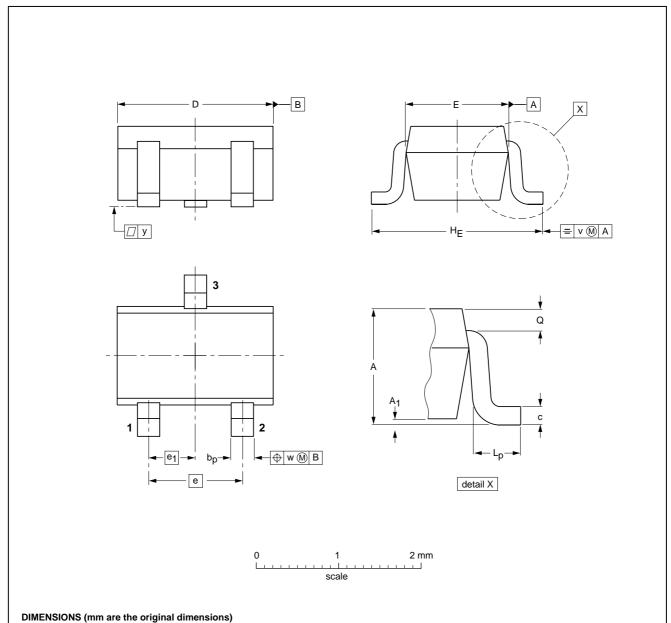
NPN switching transistors

PMST2222; PMST2222A

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT323



OUTLINE		REFER	RENCES	EUROPEAN	ICCLIE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT323			SC-70		97-02-28

e₁

0.65

 H_{E}

Lp

0.45 0.15 Q

0.23 0.13

0.2

0.2

е

1.3

1999 Apr 22 5

0.25 0.10 2.2 1.8 1.35 1.15

Α₁

max

0.1

bp

UNIT

mm

NPN switching transistors

PMST2222; PMST2222A

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
- The product status of device(s) described in this document may have changed since this document was published
 and may differ in case of multiple devices. The latest product status information is available on the Internet at
 URL http://www.nxp.com.

DISCLAIMERS

General — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions

above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors. No changes were made to the content, except for the legal definitions and disclaimers.

Contact information

For additional information please visit: http://www.nxp.com

For sales offices addresses send e-mail to: salesaddresses@nxp.com

© NXP B.V. 2009

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

 Printed in The Netherlands
 115002/00/02/pp7
 Date of release: 1999 Apr 22
 Document order number: 9397 750 05756



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

NXP:

PMST2222A,115 PMST2222,115